

Vishay Siliconix

Automotive Dual N-Channel 60 V (D-S) 175 °C MOSFET

DESCRIPTION

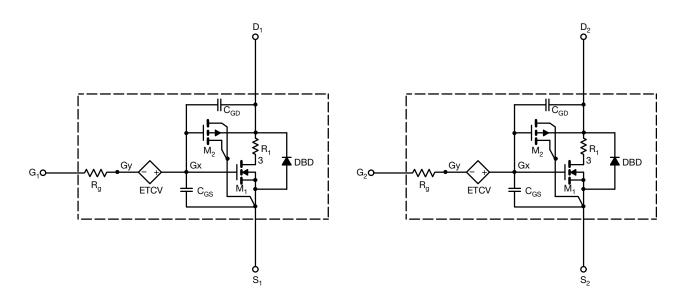
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over -55 °C to +125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- N-channel vertical DMOS
- Macro model (subcircuit model)
- Level 3 MOS
- Apply for both linear and switching application
- Accurate over -55 °C to +125 °C temperature range
- · Model the gate charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits



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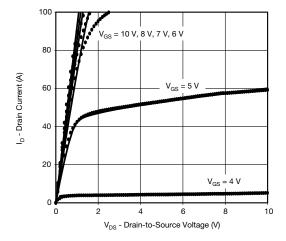
SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	3	3	V
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 10 V, I _D = 10 A	0.0107	0.0105	Ω
Forward transconductance a	9 _{fs}	V _{DS} = 15 V, I _D = 10 A	38	36	S
Diode forward voltage	V _{SD}	I _F = 10 A	0.84	0.85	V
Dynamic ^b					
Input capacitance	C _{iss}		1400	1300	
Output capacitance	C _{oss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	526	550	pF
Reverse transfer capacitance	C _{rss}		33	28	ı
Total gate charge	Q_g		17	20	
Gate-source charge	Q _{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 1.5 \text{ A}$	5.3	6	nC
Gate-drain charge	Q _{gd}		3	3	

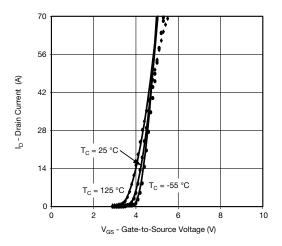
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing

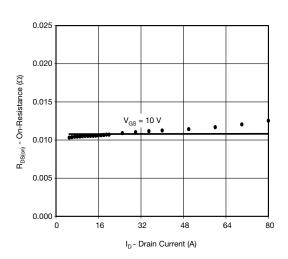
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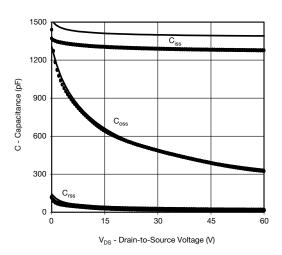
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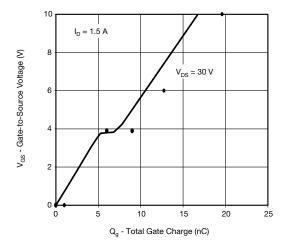
COMPARISON OF MODEL WITH MEASURED DATA (T_J = 25 °C, unless otherwise noted)

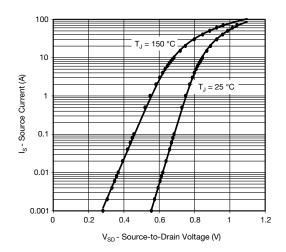












Note

 Dots and squares represent measured data Copyright: Vishay Intertechnology, Inc.



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